RV1S9213A

R08DS0187EJ0100
Rev.1.00
Nov 11,2019

1 Mbps, OPEN COLLECTOR OUTPUT, HIGH CMR, IPM DRIVER,
5-PIN SSOP WITH 8.2mm CREEPAGE DISTANCE (LSSO5) PHOTOCOUPLER

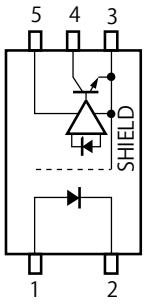
DESCRIPTION

The RV1S9213A is an optically coupled isolator containing an AlGaAs LED on the input side and a photo diode and a signal processing circuit on the output side on one chip. The RV1S9213A is designed specifically for high common mode transient immunity (CMR) and low pulse width distortion with operating temperature. It is suitable for IPM drive. This package is very small and thin with long creepage distance(8.2mm).
This small product is suitable for various interface circuits which require surface mounting and high-density mounting.

FEATURES

- Small and long creepage (8.2 mm, LSSO5)
- Open collector output
- High speed switching (t_{PHL} = 500ns Max., t_{PLH} = 750ns MAX.)
- Propagation Delay Difference ($t_{PLH} - t_{PHL}$ = 270 ns TYP.)
- Operating temperature （-40 ~ +125°C）
- High common mode transient immunity (CM_H, CM_L = ±50 kV/μs MIN.）
- High isolation voltage (BV = 5000 Vr.m.s.）
- Embossed tape product ：RV1S9213ACCSP-10Yx#KC0: 3500 pcs/reel
- Pb-Free product
- Safety standard
  - UL ：UL1577, Double protection
  - CSA ：CAN/CSA-C22.2 No.62368-1, Reinforced insulation
  - VDE ：DIN EN 60747-5-5 (Option)

PIN CONNECTION
(Top View)



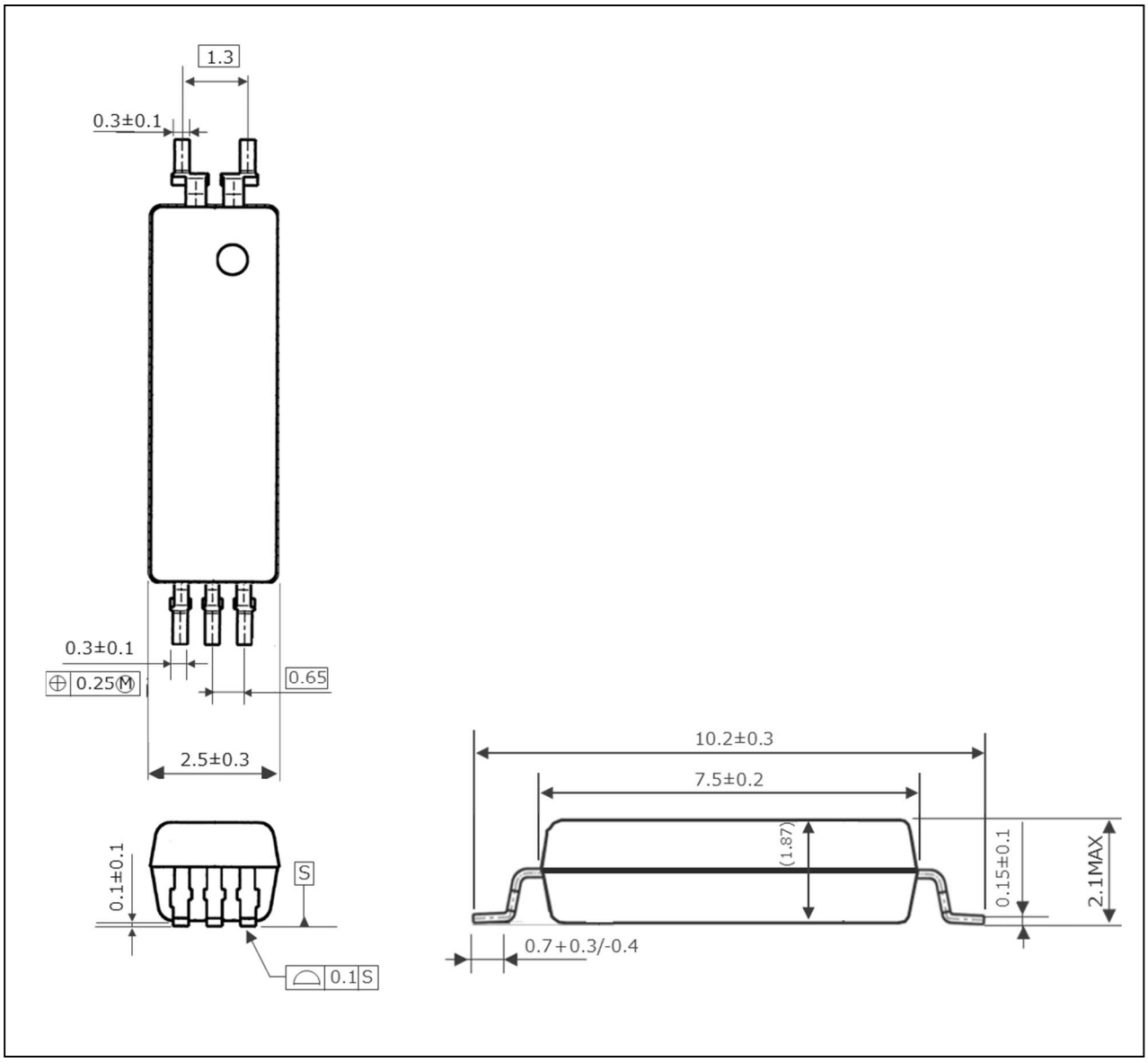
1. Anode
2. Cathode
3. GND
4. V_O
5. V_{CC}

APPLICATIONS

- Robot controller
- Industrial inverter
- AC Servo
- FA Network
- Measurement equipment

Start of mass production
Nov.2019

PACKAGE DIMENSIONS (UNIT : mm)

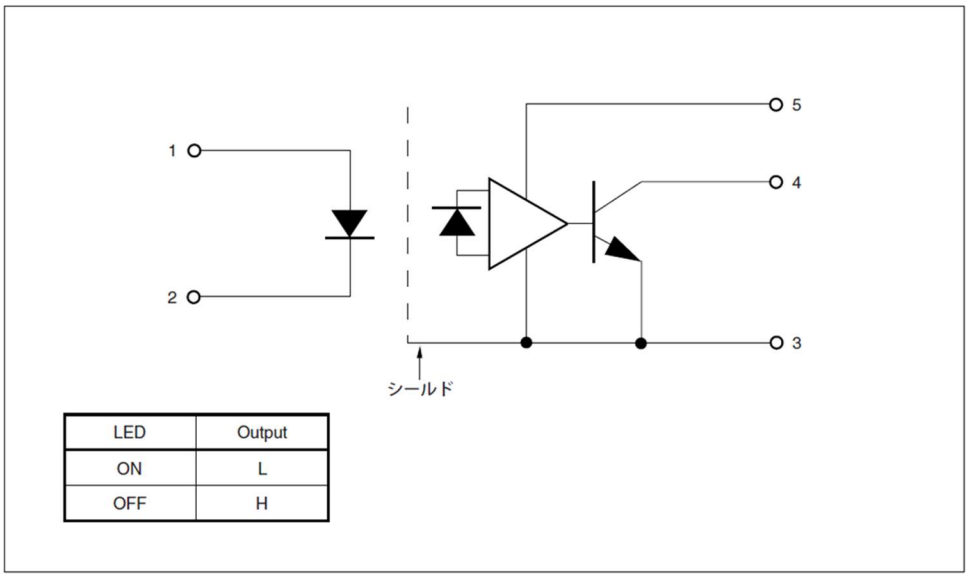


Weight :0.075g（Typ.）

PHOTOCOUPLER CONSTRUCTION

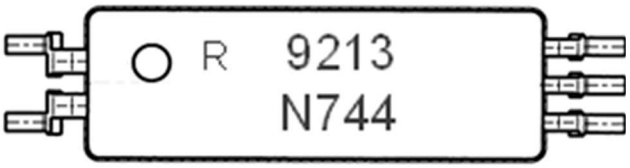
Parameter	MIN.
Air Distance	8.2 mm
Creepage Distance	8.2 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM



LED	Output
ON	L
OFF	H

MARKING EXAMPLE



R		An initial of "Renesas"	
9213		Product Part Number＊	
○		No.1 pin Mark	
N744	N	Rank Code	
	744	Assembly Lot	
		7	Last one-digit of Assembly Year
		44	Weekly Serial Code

＊）Applicable type numbers listed below

RV1S 9213 ACCSP-10Yx

Marking type number. ”RV1S” and “ACCSP-10Yx”” are omitted from original type number

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
RV1S9213ACCSP-10YC	RV1S9213ACCSP-10YC#SC0	Pb-Free and Halogen Free (Ni/Pd/Au)	20 pcs(Tape 20 pcs cut)	Standard products (UL, CSA approved)	RV1S9213A
	RV1S9213ACCSP-10YC#KC0		Embossed Tape 3500 pcs/reel		
RV1S9213ACCSP-10YV	RV1S9213ACCSP-10YV#SC0		20 pcs(Tape 20 pcs cut)	UL, CSA, DIN EN 60747-5-5 approved	
	RV1S9213ACCSP-10YV#KC0		Embossed Tape 3500 pcs/reel		

Notes:*1. For the application of the Safety Standard, following part number should be used.

ABSOLUTELY MAXIMUM RATINGS (T_A =25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current	I_F	20	mA
	Reverse Voltage	V_R	5	V
	Power Dissipation Derating	ΔP_D/℃	1.2（T_A≧110℃）	mW/℃
	Power Dissipation	P_D	45	mW
Detector	Supply Voltage	V_{CC}	-0.5 ~ +30	V
	Output Voltage	V_O	-0.5 ~ V_{CC}	V
	Output Current	I_O	15	mA
	Power Dissipation Derating	ΔP_C/℃	4.15（T_A≧85℃）	mW/℃
	Power Dissipation	P_C	250	mW
Isolation Voltage *1		BV	5000	Vr.m.s.
Operating Ambient Temperature		T_A	-40 ~ +125	°C
Storage Temperature		T_{stg}	-55 ~ +150	°C

Notes: 1. AC Voltage for 1minite at T_A=25°C, RH=60% between input and output.
Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX	Unit
Supply Voltage	V_{CC}	4.5	15	25	V
High Level Forward Current	$I_{F(ON)}$	8	10	12	mA
Low Level forward voltage	$V_{F(OFF)}$	-2		0.8	V

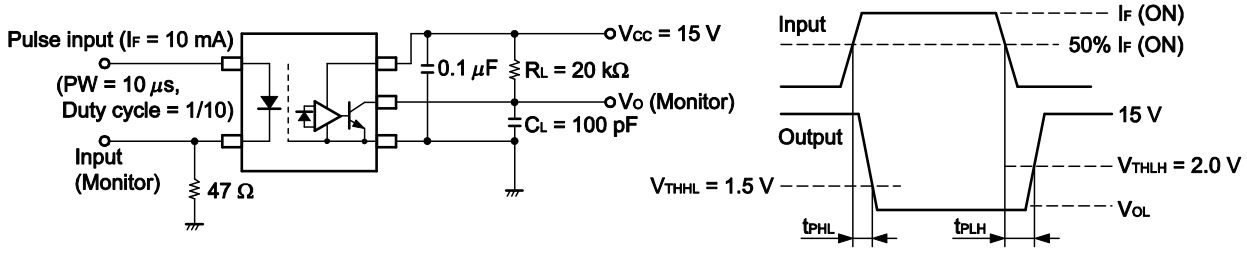
ELECTRICAL CHARACTERISTICS

(T_A = -40 ~ +125°C, VCC = 15V, unless otherwise specified)

Parameter		Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 10 mA, T_A = 25°C	1.35	1.56	1.75	V
	Reverse Current	I_R	V_R = 3 V, T_A = 25°C			10	μA
	Terminal Capacitance	C_t	V_F = 0 V, f = 1 MHz		30		pF
Detector	High Level Supply Current	I_{CCH}	V_{CC} = 20V, V_F = 0.8V, V_O = Open		1.0	1.3	mA
	Low Level Supply Current	I_{CCL}	V_{CC} = 20V, I_F =10mA, V_O = Open		1.0	1.3	mA
	High Level Output Current	I_{OH}	V_{CC} =20V, V_F =0.8V		0.01	50	μA
	Low Level Output Voltage	V_{OL}	V_{CC} = 15V, I_F =10mA, I_{OL} = 2.4mA		0.13	0.6	V
Coupled	Threshold Input Current	I_{FHL}	V_{CC} = 15V, V_O = 0.8V, I_O = 0.75mA		0.8	5.0	mA
	Isolation Resistance	R_{I-O}	V_{I-O} = 1kVDC	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	V = 0V, f = 1MHz		0.7		pF
	Propagation Delay Time (H → L)*2	t_{PHL}	V_{CC} = 15V, I_F =10mA, R_L =20kΩ, C_L = 100pF		180	500	ns
	Propagation Delay Time (L → H)*2	t_{PLH}	V_{THHL} = 1.5V, V_{THLH} = 2.0V		420	750	ns
	Propagation Delay Difference	t_{PLH}-t_{PHL}		-200	240	650	ns
	Pulse Width Distortion (PWD)*2	|t_{PHL}-t_{PLH}|			240	650	ns
	Common Mode Transient Immunity at High Level Output*3	CM_H	T_A = 25°C, I_F = 0mA, V_{CM} = 1.5kV, R_L=20kΩ C_L = 100pF, V_O >3.0V	50			kV/μs
	Common Mode Transient Immunity at Low Level Output*3	CM_L	T_A = 25°C, I_F =10mA, V_{CM} = 1.5kV, R_L=20kΩ C_L =100pF, V_O<1.0V	50			kV/μs

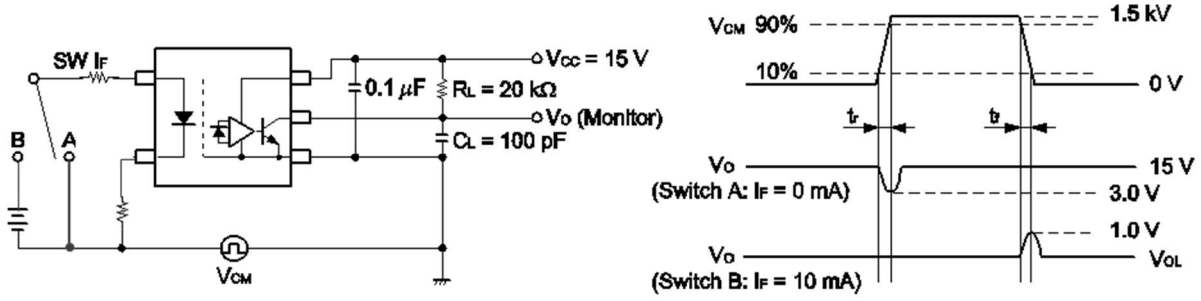
Notes*: 1. Typical values at T_A = 25°C.

2. Test circuit for propagation delay time



CL includes probe and stray wiring capacitance.

3. Test circuit for common mode transient immunity



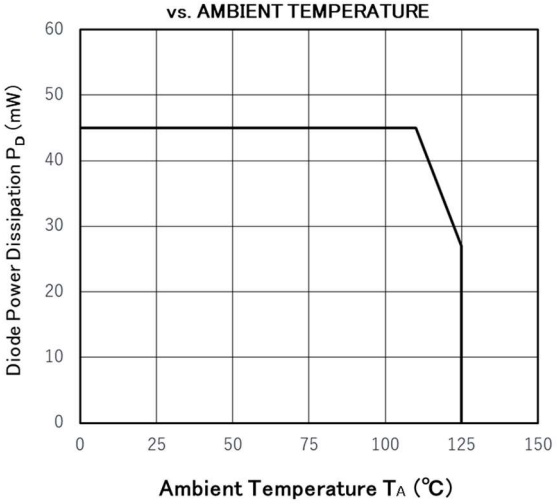
CL includes probe and stray wiring capacitance.

USAGE CAUTIONS

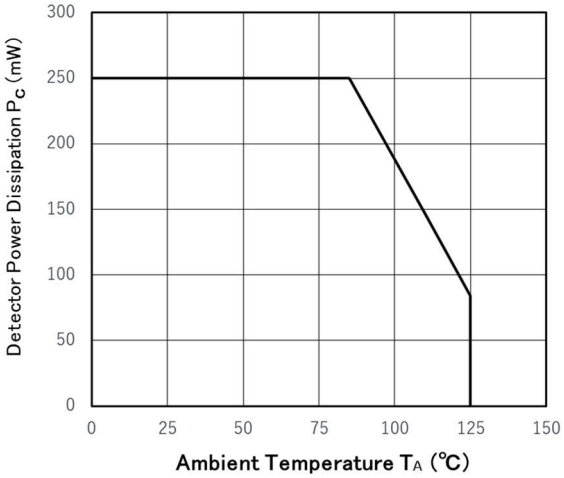
1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than 0.1 μF is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.

TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

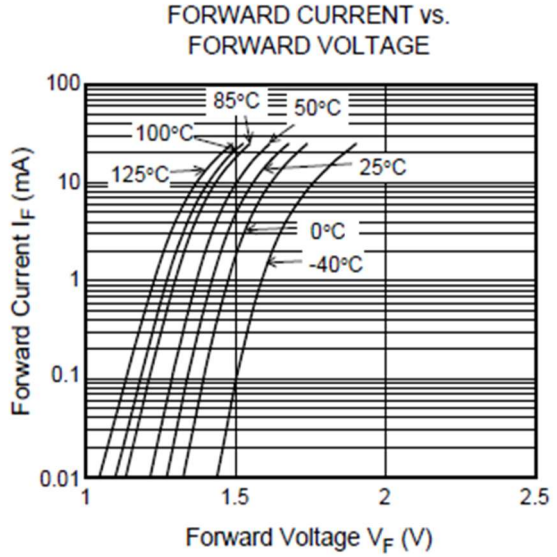
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



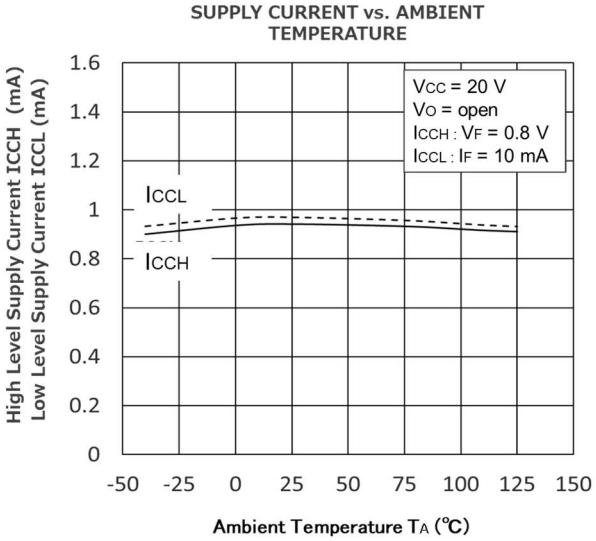
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



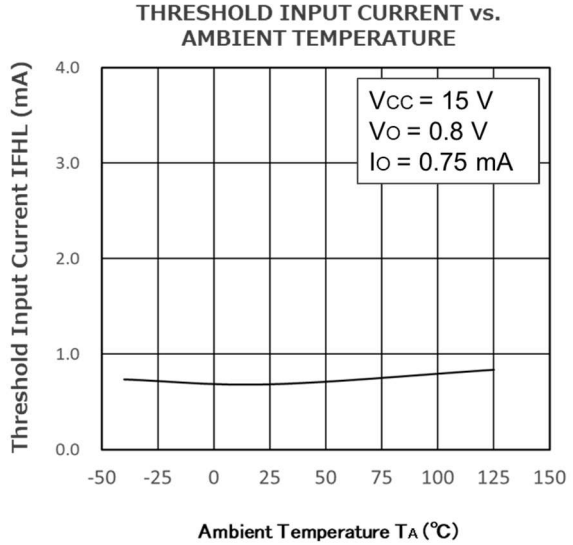
FORWARD CURRENT vs. FORWARD VOLTAGE



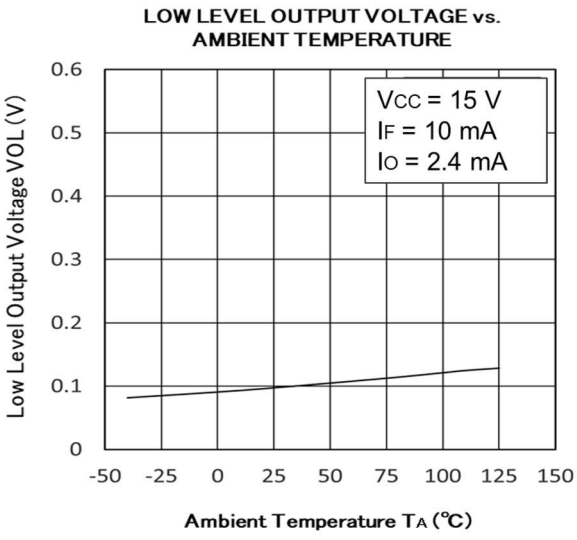
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



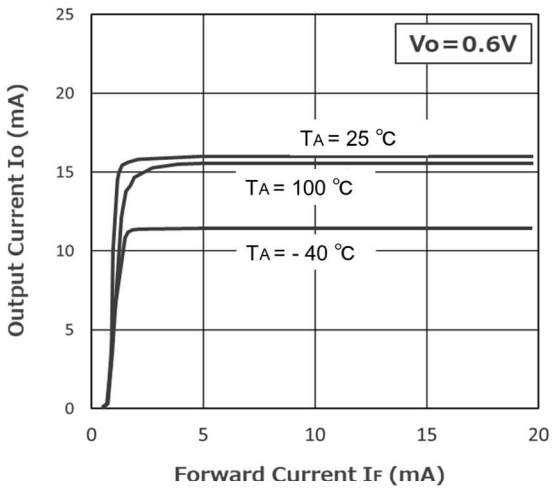
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



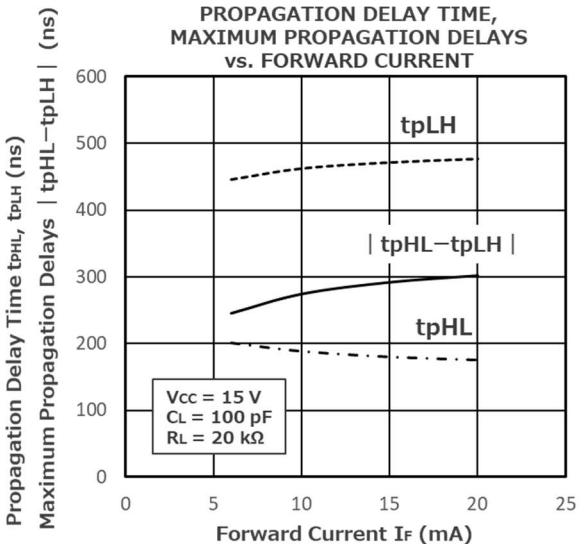
Remark The graphs indicate nominal characteristics.

TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

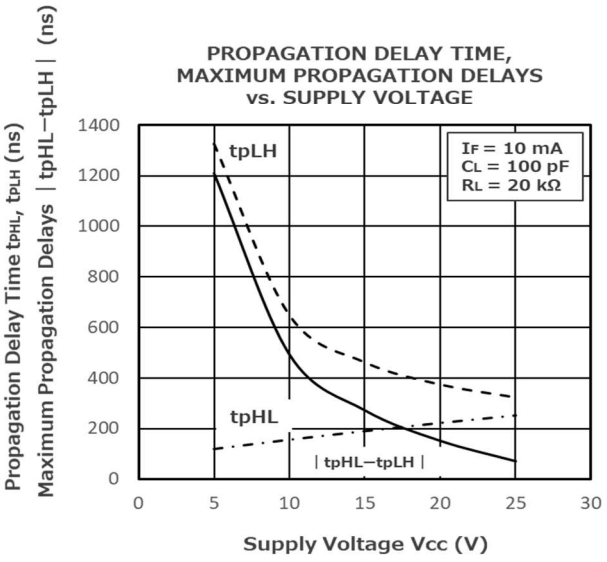
OUTPUT CURRENT vs. FORWARD CURRENT



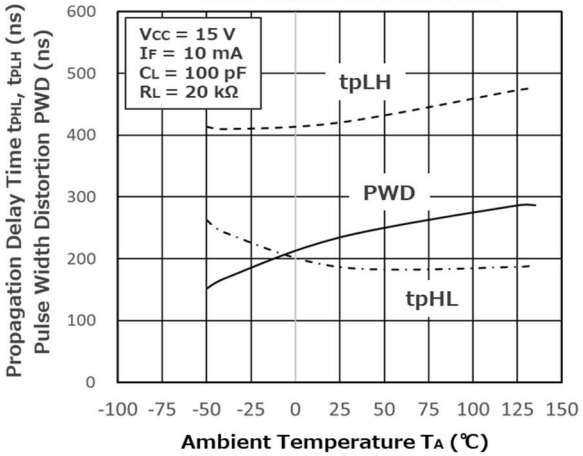
PROPAGATION DELAY TIME, MAXIMUM PROPAGATION DELAYS vs. FORWARD CURRENT



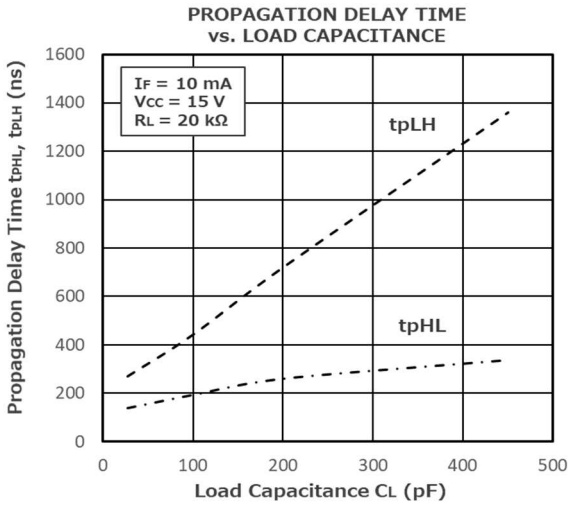
PROPAGATION DELAY TIME, MAXIMUM PROPAGATION DELAYS vs. SUPPLY VOLTAGE



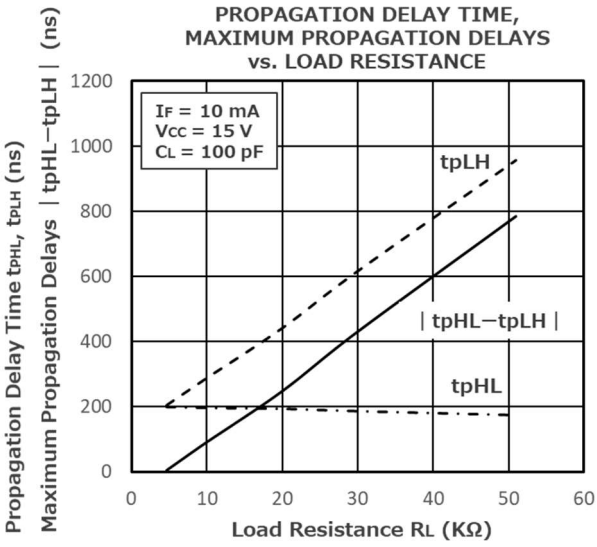
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE



PROPAGATION DELAY TIME vs. LOAD CAPACITANCE

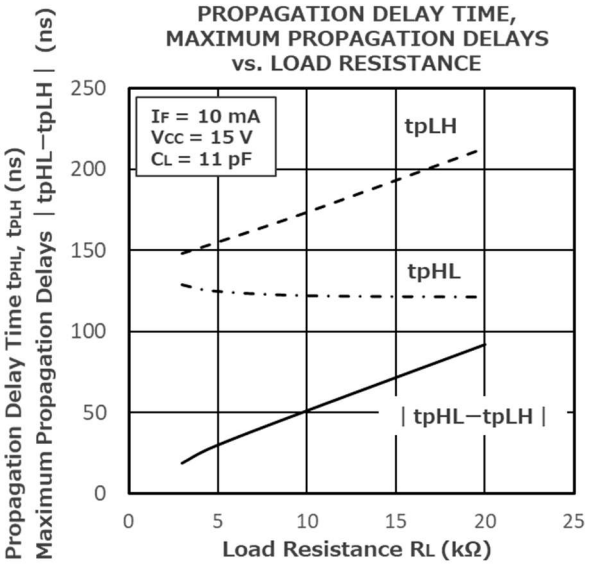


PROPAGATION DELAY TIME, MAXIMUM PROPAGATION DELAYS vs. LOAD RESISTANCE



Remark The graphs indicate nominal characteristics.

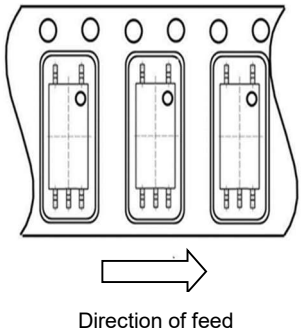
TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.

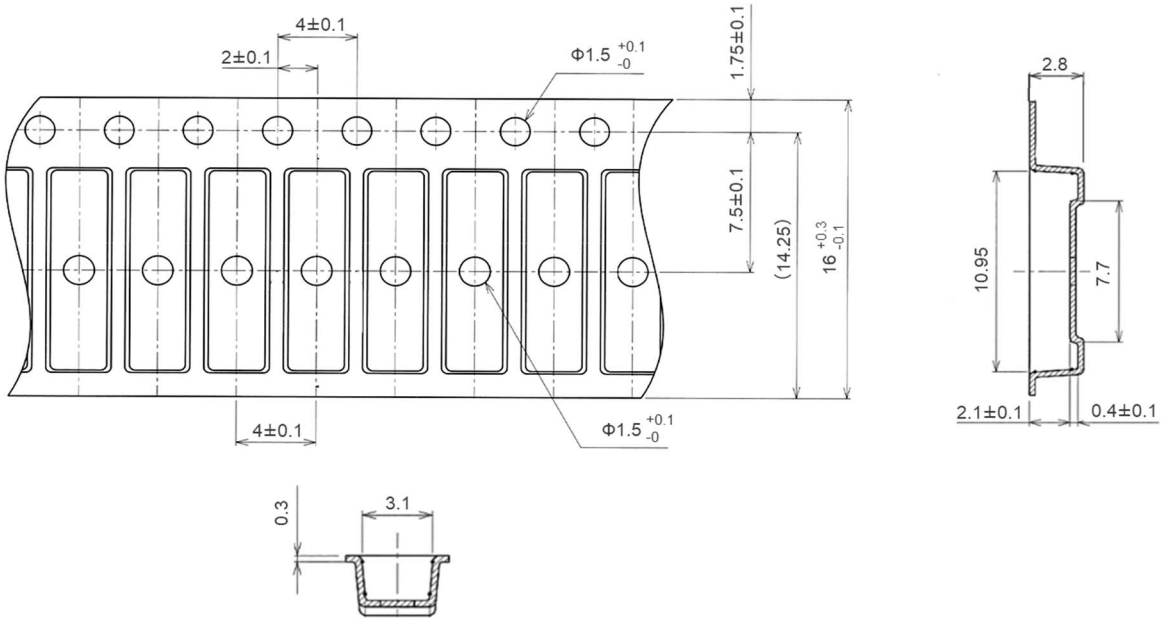
TAPING SPECIFICATIONS (UNIT : mm)

Taping Direction



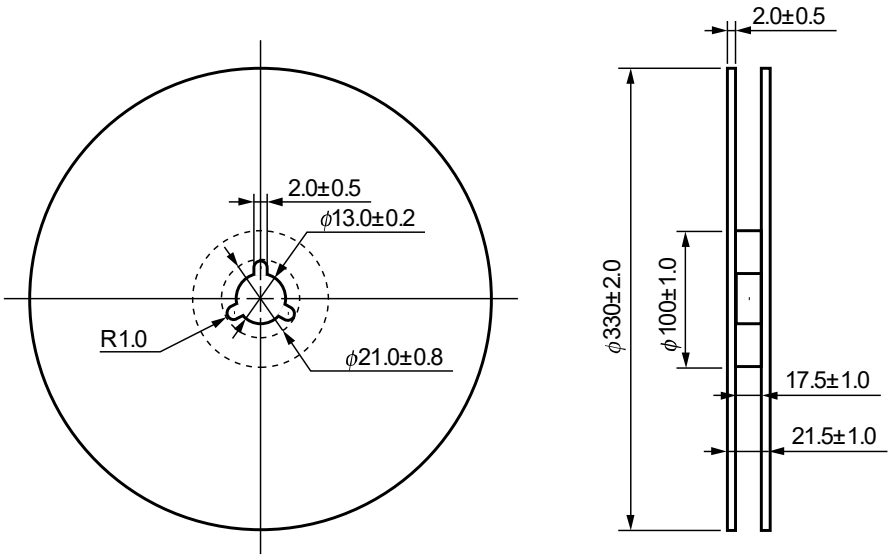
Outline and Dimensions (Tape)

Unit: mm



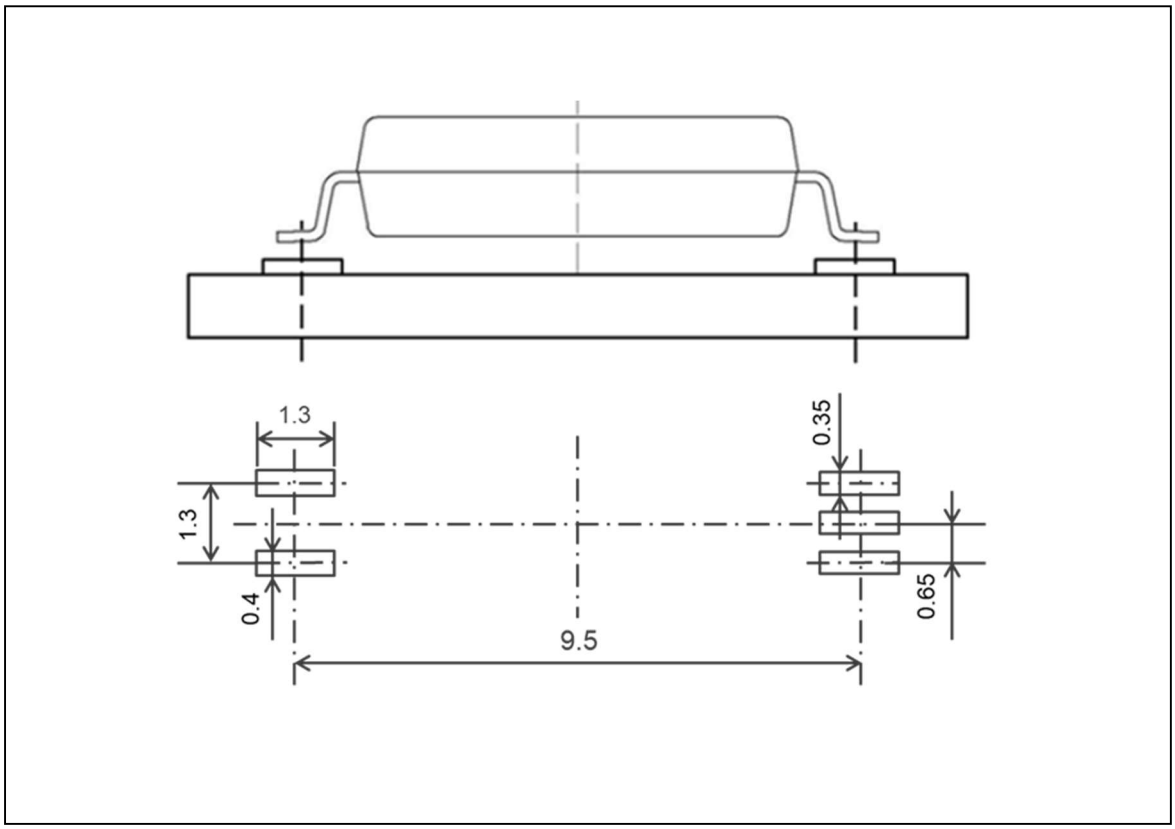
Outline and Dimensions (Reel)

Unit: mm



Packing: 3 500 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)



Remark All dimensions in this figure must be evaluated before use.

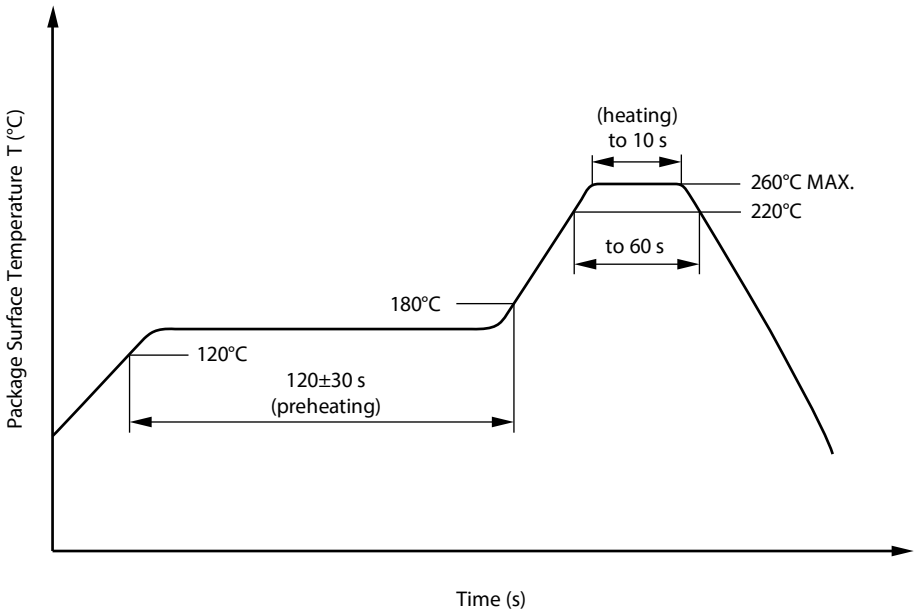
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

- Flux Cleaning
  Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use fixing agents or coatings containing halogen-based substances.

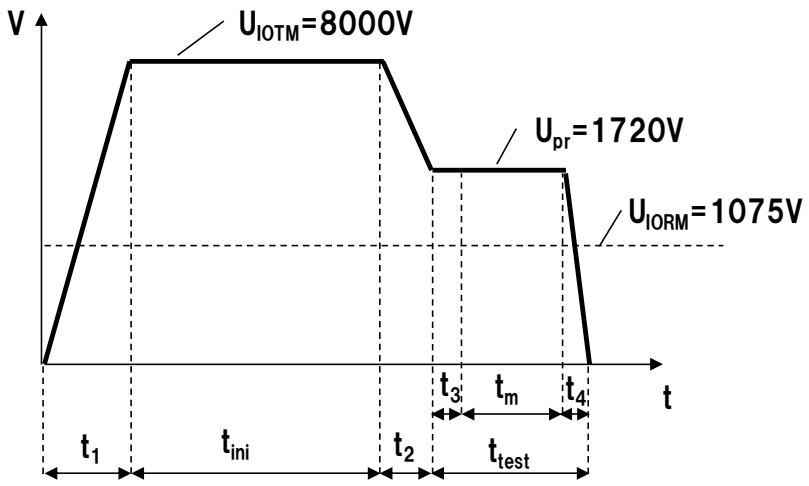
2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

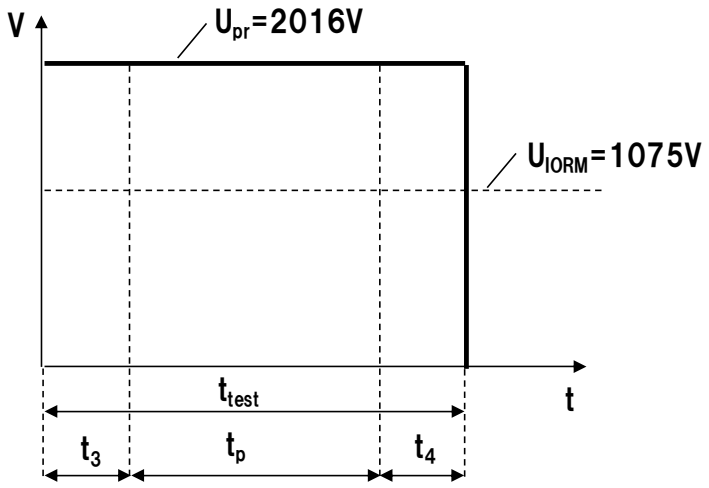
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) U_{pr} = 1.6 × $U_{IORM.}$, P_d < 5 pC	 U_{IORM} U_{pr}	 1 075 1 720	 V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) U_{pr} = 1.875 × $U_{IORM.}$, P_d < 5 pC	U_{pr}	2 016	V_{peak}
Highest permissible overvoltage	U_{IOTM}	8 000	V_{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	400	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		Ⅱ	
Storage temperature range	T_{stg}	−55～+150	°C
Operating temperature range	T_A	−40～+125	°C
Isolation resistance, minimum value V_{IO} = 500 V dc at T_A = 25°C V_{IO} = 500 V dc at T_A MAX. at least 100°C	 Ris MIN. Ris MIN.	 10^{12} 10^{11}	 Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F, Psi = 0) Power (output or total power dissipation) Isolation resistanceV_{IO} = 500 V dc at T_A = Tsi	 Tsi Isi Psi Ris MIN.	 175 400 700 10^9	 °C mA mW Ω

Method a) Destructive Test, Type and Sample Test



t_1,t_2=1 to 10 sec
t_3,t_4=1 sec
$t_{m\ (PARTIAL\ DISCHARGE)}$=10 sec
t_{test}=12 sec
t_{ini}=60 sec

Method b) Non-destructive Test, 100% Production Test



t_3,t_4=0.1 sec

$t_{p\ (PARTIAL\ DISCHARGE)}$=1.0 sec

t_{test}=1.2 sec

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.

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